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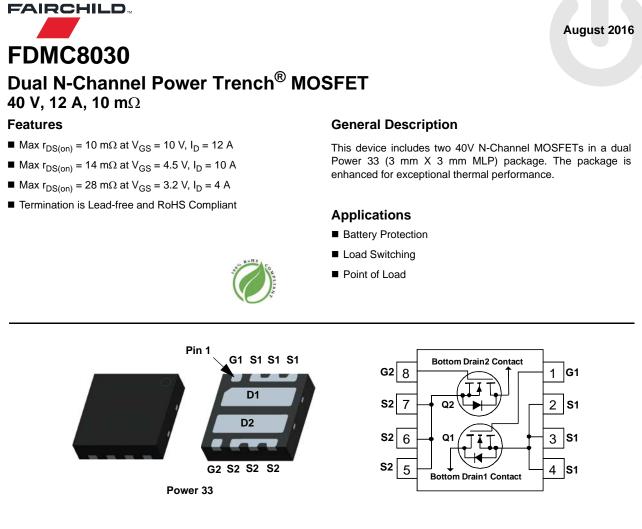


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted.

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			40	V	
V _{GS}	Gate to Source Voltage		(Note 4)	±12	V	
	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	12	^	
D	-Pulsed			50	— A	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	21	mJ	
P _D	Power Dissipation	T _C = 25 °C		14	W	
	Power Dissipation	T _A = 25 °C	(Note 1a)	1.9		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

R_{\thetaJC}	Thermal Resistance, Junction to Case	9.0	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1a	ı) 65	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1)) 155	

Package Marking and Ordering Information

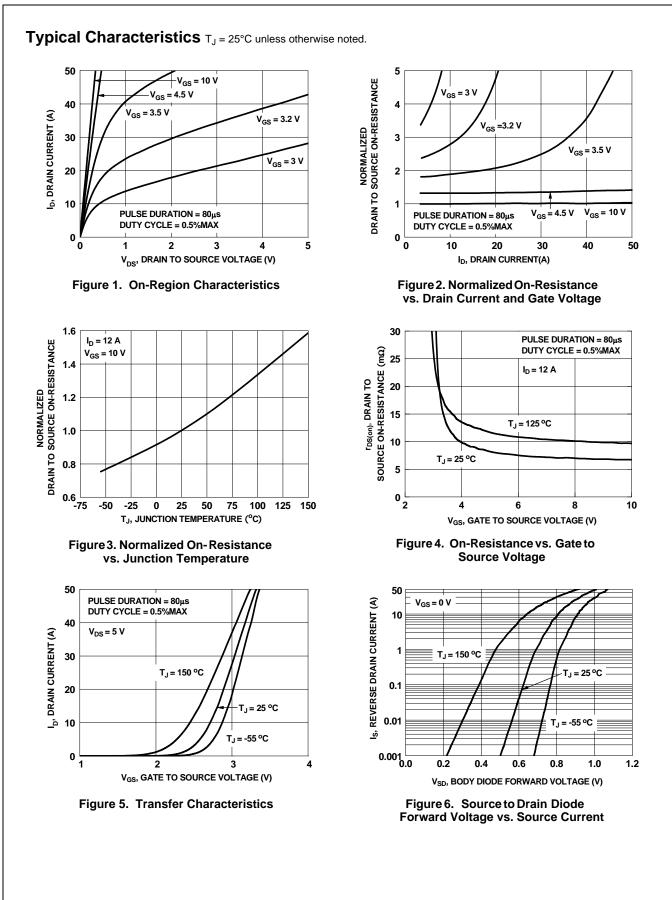
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC8030	FDMC8030	Power 33	13 "	12 mm	3000 units

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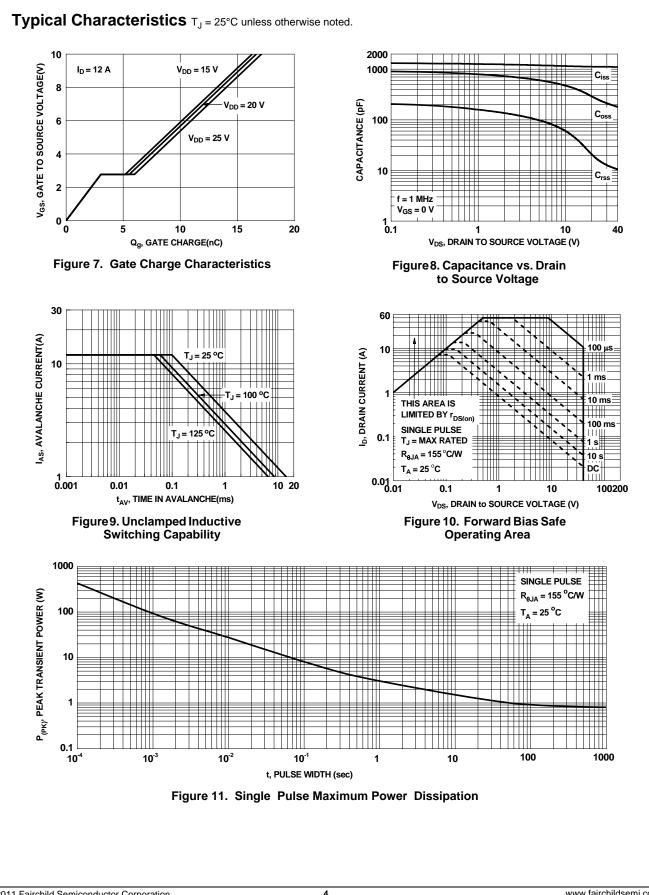
Symbol	Al Characteristics T _J = 25 °C unle Parameter	Test Conditions	Min.	Тур.	Max.	Units	
		Test conditions	141111.	Typ.	Wax.	Units	
	Icteristics		40			V	
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	40			V	
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 $\mu A,$ referenced to 25 °C		19		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 32 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current, Forward	I V _{GS} = 12 V, V _{DS} = 0 V			100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	1.5	2.8	V	
$\Delta V_{GS(th)}$	Gate to Source Threshold Voltage		1.0	1.0	2.0	v	
$\Delta V_{GS(th)}$ ΔT_{J}	Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-5		mV/°C	
		V _{GS} = 10 V, I _D = 12 A		8	10		
		$V_{GS} = 4.5 \text{ V}, \ I_D = 10 \text{ A}$		10	14		
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 3.2 \text{ V}, \ I_D = 4 \text{ A}$		19	28	mΩ	
		$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 12 \text{ A}$		13	16		
		T _J = 125 °C		15	10		
9 _{FS}	Forward Transconductance	$V_{DD} = 5 V, I_D = 12 A$		57		S	
Dvnamic	Characteristics						
C _{iss}	Input Capacitance			1462	1975	pF	
C _{oss}	Output Capacitance	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		321	430	pF	
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		20	30	pF	
R _g	Gate Resistance			0.9	2.5	Ω	
					_		
Switching	g Characteristics			1	1	-	
t _{d(on)}	Turn-On Delay Time			7	13	ns	
t _r	Rise Time	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 12 \text{ A}$		3	10	ns	
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		19	33	ns	
t _f	Fall Time			3	10	ns	
0	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		21	30	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 20 V$		12	17	nC	
Q _{gs}	Gate to Source Charge	I _D = 12 A		2.8		nC	
Q _{gd}	Gate to Drain "Miller" Charge			2.5		nC	
Drain-Sou	urce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 12 A$ (Note 2)		0.83	1.2	V	
t _{rr}	Reverse Recovery Time			25	40	ns	
Q _{rr}	Reverse Recovery Charge	— I _F = 12 A, di/dt = 100 A/μs		9	18	nC	
NOTES:	Revelee Recercity charge			Ŭ	10		
1. $R_{\theta JA}$ is determ	ined with the device mounted on a 1 in ² pad 2 oz copper pa	ad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is g	guaranteed l	oy design whi	e R $_{\theta CA}$ is de	termined by	
the user's boa	rð design.						
1			h 166 °	C/W when mo	ounted on		
	a. 65 °C/W when mounted on a 1 in ² pad of 2 oz copper			mum pad of			
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2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0 %. 3. E_{AS} of 21 mJ is based on starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 12 A, V_{DD} = 36 V, V_{GS} = 10 V. 100% tested at L = 3 mH, I_{AS} = 5 A. 4. As an N-ch device, the negative V_{gs} rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

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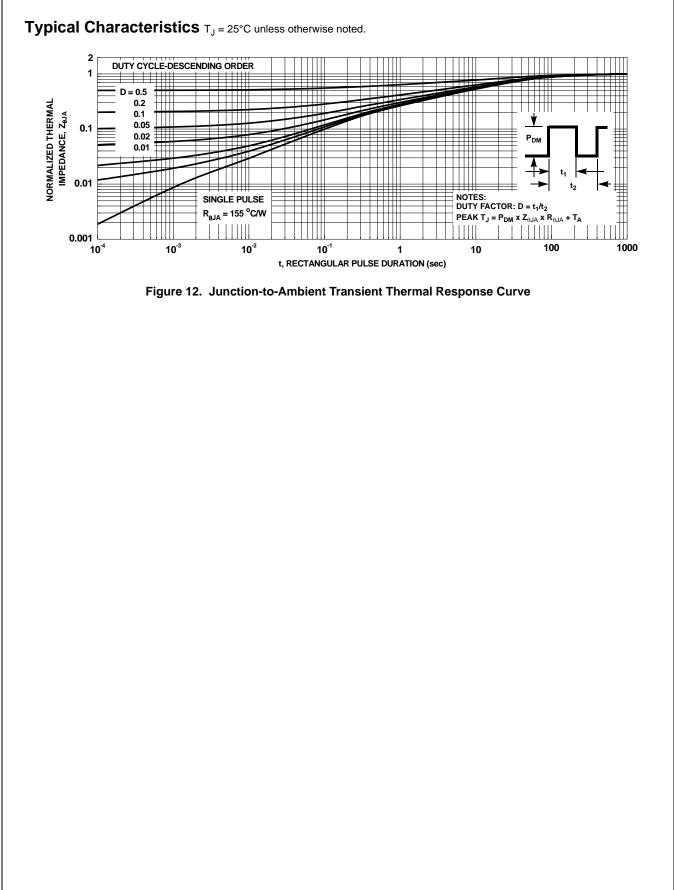
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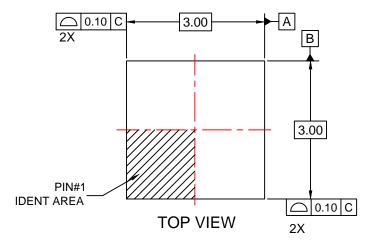
FDMC8030 Dual N-Channel Power Trench[®] MOSFET



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FDMC8030 Rev.1.3

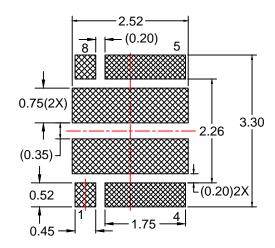
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0.80 MAX

// 0.10 C

0.08 C

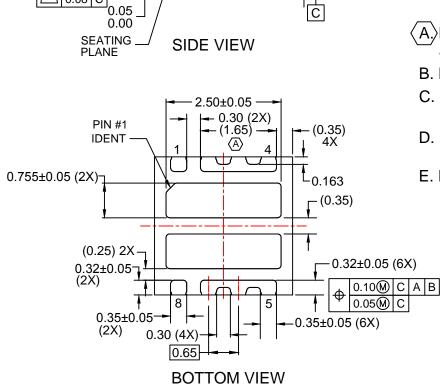


RECOMMENDED LAND PATTERN

NOTES:

(0.20)

- A DOES NOT FULLY CONFORM TO JEDEC REGISTRATION, MO-229.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY
- E. DRAWING FILE NAME: MKT-MLP08Xrev2.



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